NSN 5961-01-338-5496

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-338-5496

Inclosure Material:
Glass
Overall Length:
Between 20.07 millimeters and 20.32 millimeters
Terminal Length:
Between 13.46 millimeters and 28.48 millimeters
Overall Height:
Between 6.32 millimeters and 6.60 millimeters
Overall Width:
Between 13.59 millimeters and 13.84 millimeters
Mounting Facility Quantity:
1
Internal Configuration:
Field effect
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-254
Mounting Method:
Terminal and unthreaded hole
Features Provided:
Hermetically sealed case and electrostatic sensitive
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
20.0 gate to source voltage
Current Rating Per Characteristic:
24.00 amperes drain current
Power Rating Per Characteristic:
125.0 watts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Special Features:
Nuclear hardness critical item
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No

NSN 5961-01-338-5496 Transistor - Page 2 of 2

Fiig: A110a0

